



1

	Program of Electronic Devices and Systems
LSI LSI	

A

B

C

D

E

A D

E

1 2

34

S=4 A=3 B=2 C=1

(Excellent)

(Very

Good)

(Good)

90	
80 89	
70 79	
60 69	

(Excellent)	3.00 4.00
(Very Good)	2.00 2.99
(Good)	1.00 1.99

()

1

2

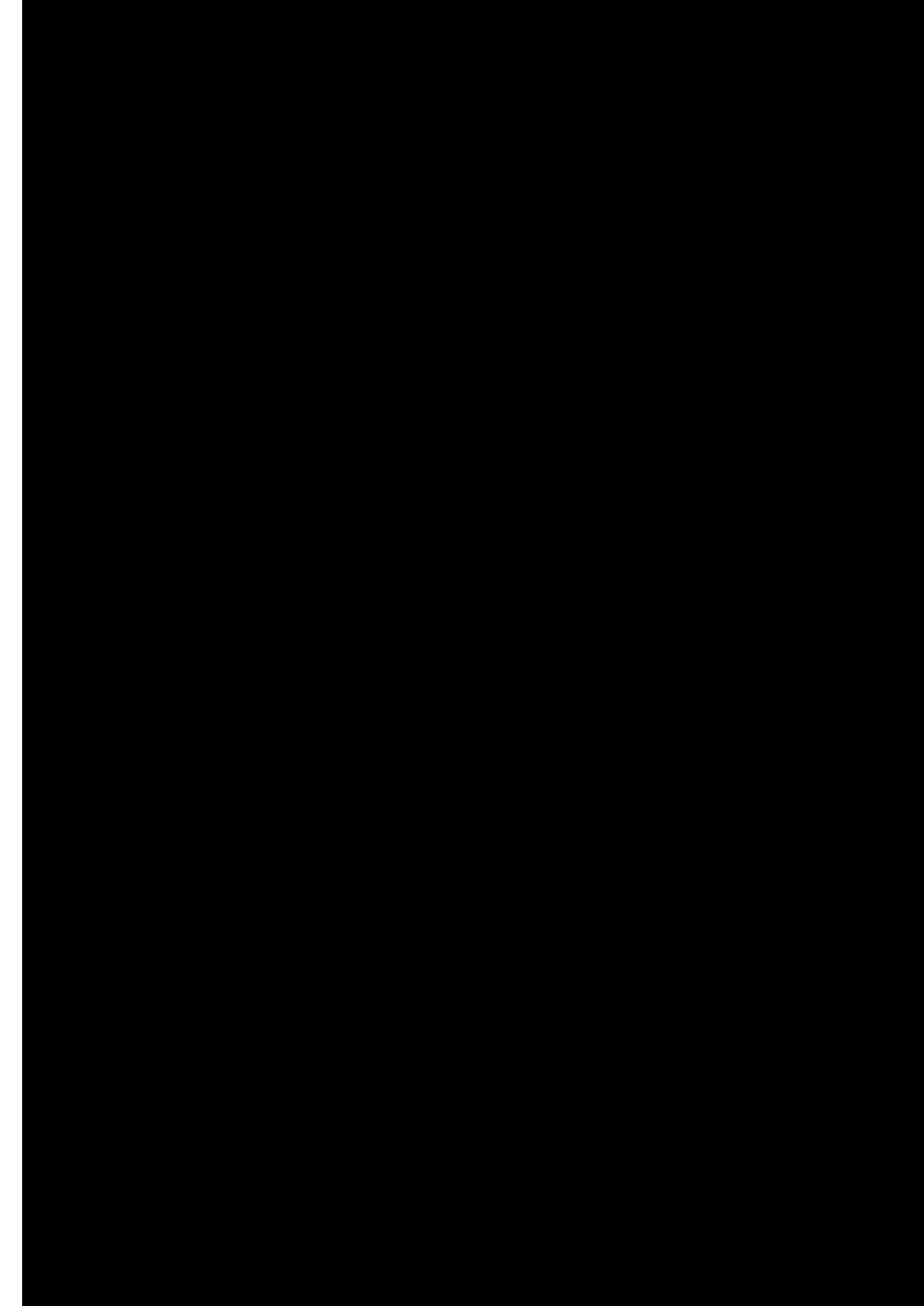
3
4
5
6

(plan) (do) (check) (action)

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T T T T T T T T T T T T T T T

2	2
2	2
2	2
0	1
4	2
4	2
	1
	1
	1
	1



(Excellent)

(Very Good)

(Good)

(1)

(2)

(3)

(4)

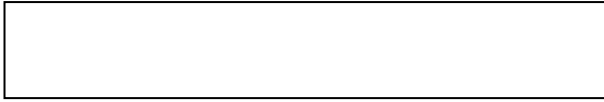
(1)

(2)

(3)

(4)

(5)



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